NSN 5961-01-347-5851

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-347-5851 **Inclosure Material:** Metal and ceramic **Overall Length:** Between 0.500 inches and 0.560 inches **Overall Diameter:** Between 1.610 inches and 1.650 inches **End Application:** Radar set an/mpn-14k **Mounting Method:** Compression **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1400.0 repetitive peak off-state voltage and 1400.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 150.00 amperes drain current universal **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 case and 2 insulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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